

## isc Triacs

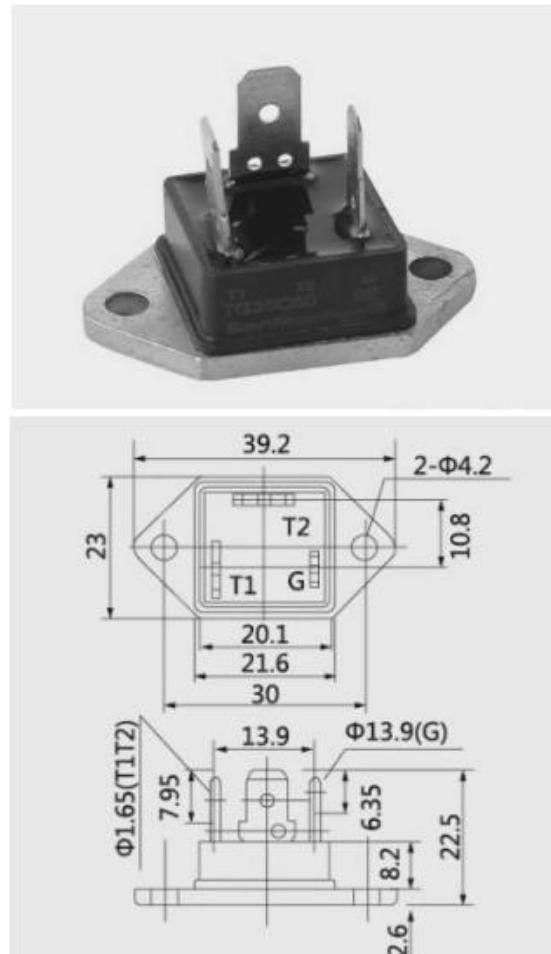
## BTA60-800B

### FEATURES

- With TOP3 insulated package
- Suitables for general purpose where high surge current capability is required.  
Application such as phase control and static switching on inductive or resistive load.

ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	MIN	UNIT
$V_{DRM}$	Repetitive peak off-state voltage	800	V
$V_{RRM}$	Repetitive peak reverse voltage	800	V
$I_{T(RMS)}$	RMS on-state current (full sine wave) $T_j=80^\circ\text{C}$	60	A
$I_{TSM}$	Non-repetitive peak on-state current $t_p=20\text{ms}$	900	A
$T_j$	Operating junction temperature	-40-125	°C
$T_{stg}$	Storage temperature	-40~150	°C
$P_{G(AV)}$	Average gate power dissipation( $T_j=125^\circ\text{C}$ )	1	W
$R_{th(j-c)}$	Thermal resistance, junction to case	0.9	°C /W



**ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$  unless otherwise specified)**

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
$I_{RRM}$	Repetitive peak reverse current	$V_R=V_{RRM}$ , $V_R=V_{RRM}, T_j=125^\circ\text{C}$	0.02 2.0	mA
$I_{DRM}$	Repetitive peak off-state current	$V_D=V_{DRM}$ , $V_D=V_{DRM}, T_j=125^\circ\text{C}$	0.02 2.0	mA
$I_{GT}$	Gate trigger current	I	50	mA
		II	50	
		III	50	
		IV	90	
$I_H$	Holding current	$I_{GT}= 0.5\text{A}$ , Gate Open	80	mA
$V_{GT}$	Gate trigger voltage all quadrant	$V_D=12\text{V}; R_L= 100 \Omega$	1.5	V
$V_{TM}$	On-state voltage	$I_{TM}= 120\text{A};$	1.55	V